

P-Channel 30 V (D-S) MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	-30				
$R_{DS(on)}$ max. (Ω) at $V_{GS} = 10 \text{ V}$	0.0015				
$R_{DS(on)}$ max. (Ω) at $V_{GS} = 7.5 \text{ V}$	0.0023				
Q _g typ. (nC)	170				
I _D (A) ^a	-227				
Configuration	Single				

FEATURES

 Leadership R_{DS(on)} minimizes power loss from conduction



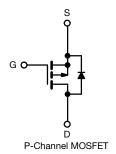
COMPLIANT

HALOGEN **FREE**

- 100 % R_q and UIS tested
- Enhance power dissipation and lower R_{thJC}
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- · Adapter and charger switch
- · Load switch
- Motor drive control
- · Battery management



ORDERING INFORMATION	
Package	PowerPAK SO-8S
Lead (Pb)-free and halogen-free	SiRS4301DP-T1-GE3

PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	-30	V	
Gate-source voltage		V _{GS}	± 20	v	
Continuous drain current (T _J = 150 °C)	T _C = 25 °C		-227		
	T _C = 70 °C	1 . \square	-182		
	T _A = 25 °C	I _D	-53.7 ^{b, c}		
	T _A = 70 °C	1	-43.0 ^{b, c}	Α	
Pulsed drain current (t = 100 μs)		I _{DM}	-350	A	
Continuous source-drain diode current	T _C = 25 °C		-110		
	T _A = 25 °C	l _s	-6.1 b, c		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	-50		
Single pulse avalanche energy		E _{AS}	125	mJ	
Maximum power dissipation	T _C = 25 °C		132		
	T _C = 70 °C		84	w	
	T _A = 25 °C	P _D	7.4 ^{b, c}	VV	
	T _A = 70 °C	1 -	4.7 ^{b, c}		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +150	°C	
Soldering recommendations (peak temperature) c			260	-0	

THERMAL RESISTANCE RATIN	GS				
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient ^b	t ≤ 10 s	R_{thJA}	13	17	°C/W
Maximum junction-to-case (drain)	Steady state	R_{thJC}	0.73	0.95	C/VV

Notes

- a. $T_C = 25$ °C
- b. Surface mounted on 1" x 1" FR4 board
- t = 10 s
- See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8S is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components Maximum under steady state conditions is 45 °C/W



PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static			•			
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-30	-	-	V
V _{DS} temperature coefficient	$\Delta V_{DS}/T_{J}$	I _D = -10 mA	-	-30	-	>//90
V _{GS(th)} temperature coefficient	$\Delta V_{GS(th)}/T_J$	I _D = -250 μA	-	5.6	-	mV/°C
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-1	-	-2.3	V
Gate-source leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA
Zana mata walta sa alusia assumant	I _{DSS}	V _{DS} = -30 V, V _{GS} = 0 V	-	-	1	μΑ
Zero gate voltage drain current		V _{DS} = -30 V, V _{GS} = 0 V, T _J = 55 °C	-	-	10	
Davis and a state of the same	_	$V_{GS} = -10 \text{ V}, I_D = -20 \text{ A}$	-	0.0012	0.0015	_
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -20 \text{ A}$	-	0.0018	0.0023	Ω
Forward transconductance a	9 _{fs}	$V_{DS} = -15 \text{ V}, I_{D} = -20 \text{ A}$	-	125	-	S
Dynamic ^b			•			
Input capacitance	C _{iss}		-	19 750	-	
Output capacitance	C _{oss}	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	2070	-	pF
Reverse transfer capacitance	C _{rss}	V _{DS} = -13 V, V _{GS} = 0 V, 1 = 1 Will 2		1175	-	
Total gate charge	Qg	$V_{DS} = -10 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -20 \text{ A}$	-	365	548	
			-	170	255	
Gate-source charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -20 \text{ A}$	-	64	-	nC
Gate-drain charge	Q _{gd}	DS = 10 1, 1GS = 1.0 1, 1D = 20 /1		55	-	1
Output charge	Q _{oss}	V _{DS} = -15 V, V _{GS} = 0 V	-	43	-	
Gate resistance	R _q	f = 1 MHz	0.5	2.4	4.8	Ω
Turn-on delay time	t _{d(on)}		-	22	44	
Rise time	t _r	$V_{DD} = -15 \text{ V}, R_L = 1.5 \Omega, I_D \cong -10 \text{ A},$	-	28	56	
Turn-off delay time	t _{d(off)}	$V_{DD} = -15 \text{ V}, R_L = 1.5 \Omega, I_D \cong -10 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$		210	420	1
Fall time	t _f		-	90	180	1
Turn-on delay time	t _{d(on)}		-	80	160	ns
Rise time	t _r	$V_{DD} = -15 \text{ V}, R_L = 1.5 \Omega, I_D \cong -10 \text{ A},$	-	160	320	
Turn-off delay time	t _{d(off)}	$V_{GEN} = -4.5 \text{ V}, R_g = 1 \Omega$	-	210	420	
Fall time	t _f		-	140	280	
Drain-Source Body Diode Characteristi	cs		•			
Continuous source-drain diode current	I _S	T _C = 25 °C	-	-	110	_
Pulse diode forward current	I _{SM}		-	-	350	A
Body diode voltage	V _{SD}	$I_S = -10 \text{ A}, V_{GS} = 0 \text{ V}$	-	0.75	1.2	V
Body diode reverse recovery time	t _{rr}		-	48	96	ns
Body diode reverse recovery charge	Q _{rr}	$I_F = -10 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s},$	-	51	102	nC
Reverse recovery fall time	t _a	$T_J = 25 ^{\circ}\text{C}$	-	23	-	
•	t _b		-	25	-	ns

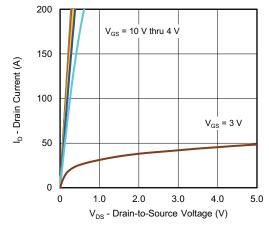
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing

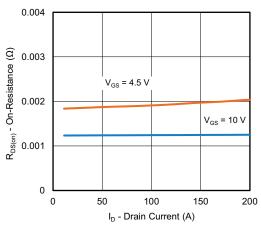
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



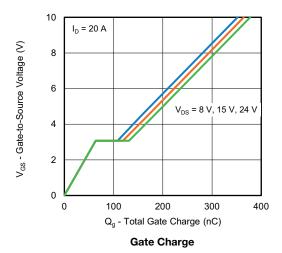
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

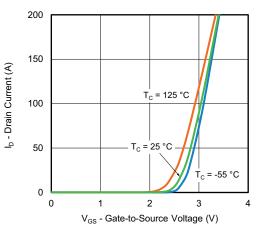


Output Characteristics

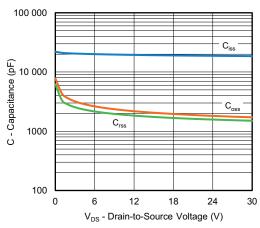


On-Resistance vs. Drain Current and Gate Voltage

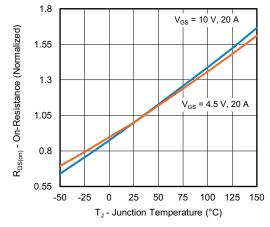




Transfer Characteristics



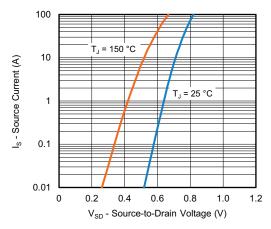
Capacitance



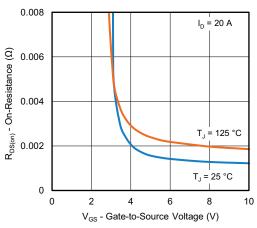
On-Resistance vs. Junction Temperature



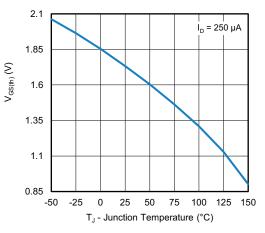
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



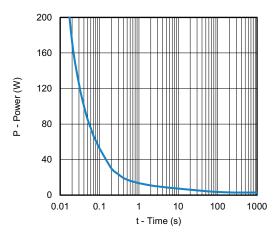
Source-Drain Diode Forward Voltage



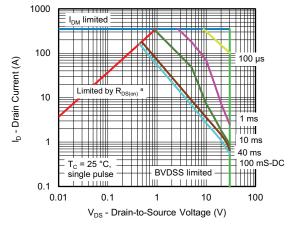
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



Single Pulse Power, Junction-to-Ambient

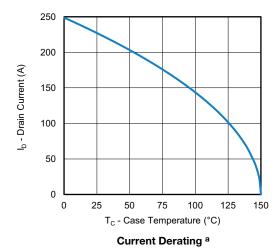


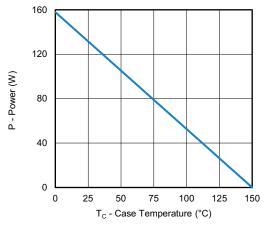
Safe Operating Area, Junction-to-Case

Note

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





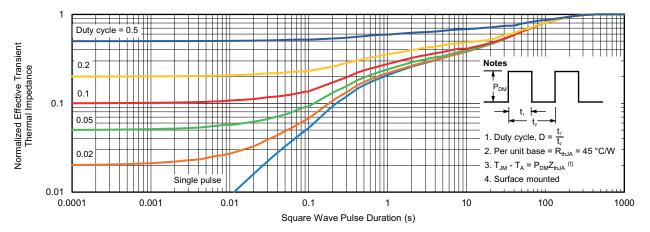
Power, Junction-to-Case

Note

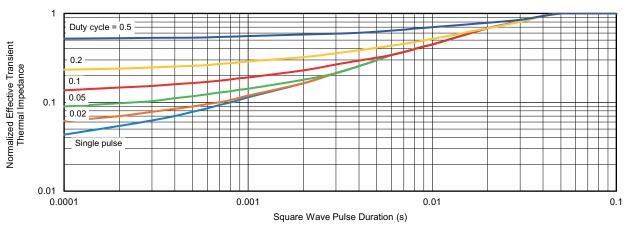
a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

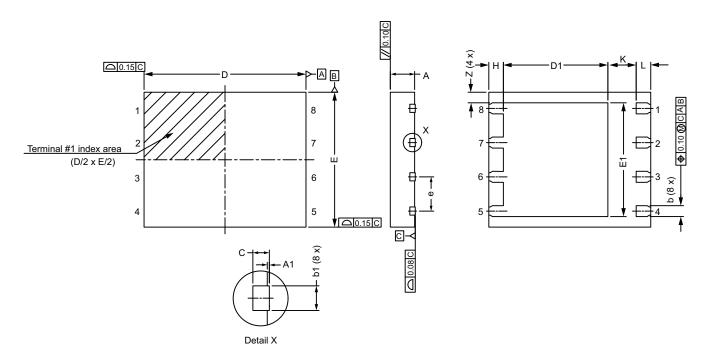


Normalized Thermal Transient Impedance, Junction-to-Case

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PowerPAK® SO-8S BWL

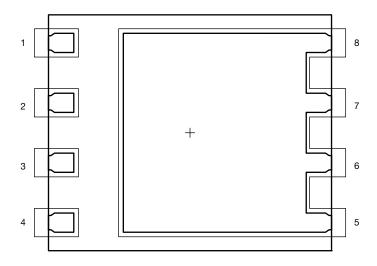


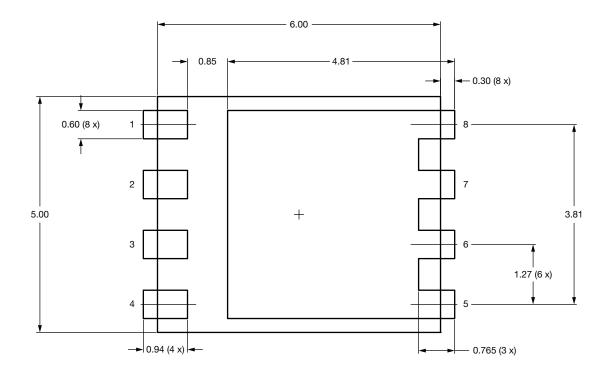
DIM.		MILLIMETERS			INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
Α	0.85	0.90	0.95	0.033	0.035	0.037		
A1	-	-	0.05	-	-	0.002		
b	0.31	0.41	0.51	0.012	0.016	0.020		
b1	0.20	0.30	0.40	0.008	0.012	0.016		
С		0.20 ref.			0.008 ref.			
D	5.90	6.00	6.10	0.232	0.236	0.240		
D1	3.78	3.88	3.98	0.149	0.153	0.157		
E	4.90	5.00	5.10	0.193	0.197	0.201		
E1	4.12	4.22	4.32	0.162	0.166	0.170		
е		1.27 BSC			0.050 BSC			
Н	0.44	0.54	0.64	0.017	0.021	0.025		
K		1.05 ref.			0.041 ref.			
L	0.44	0.54	0.64	0.017	0.021	0.025		
Z		0.39 ref.			0.015 ref.			

DWG: 6082



Recommended Land Pattern PowerPAK® SO-8S BWL







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